NSN 5961-01-046-9560

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-046-9560 **Inclosure Material:** Metal **Overall Length:** 0.394 inches **Overall Diameter:** 0.349 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** Between 0.424 inches and 0.437 inches **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 breakdown voltage, collector-to-base, emitter open and 80.0 breakdown voltage, collector-to-emitter, base open and 6.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** Between 2.00 amperes source cutoff current and 5.00 amperes source cutoff current **Power Rating Per Characteristic:** 50.0 watts small-signal input power, common-collector **Special Features:** Junction pattern arrangement: npn **Thread Series Designator:** Unf **Terminal Type And Quantity:** 2 tab, solder lug and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:**

Fiig: A110a0

No